J. Org. Chem., 1996, 61(21), 7326-7334, DOI:10.1021/jo960911k

## Terms \& Conditions

Electronic Supporting Information files are available without a subscription to ACS Web Editions. The American Chemical Society holds a copyright ownership interest in any copyrightable Supporting Information. Files available from the ACS website may be downloaded for personal use only. Users are not otherwise permitted to reproduce, republish, redistribute, or sell any Supporting Information from the ACS website, either in whole or in part, in either machinereadable form or any other form without permission from the American Chemical Society. For permission to reproduce, republish and redistribute this material, requesters must process their own requests via the RightsLink permission system. Information about how to use the RightsLink permission system can be found at http://pubs.acs.org/page/copyright/permissions.html

## ACS Publications

## TABLE S1

## X-ray Crystal Structure Analysis of 3

Data were measured on an ENRAF-NONIUS CAD-4 Computer-Controlled Diffractometer. $\mathrm{CuK}_{\alpha}(\lambda=1.54178 \AA)$ radiation with a graphite crystal monochromator in the incident beam was used. The standard CAD-4 centering, indexing, and data collection programs were used. The unit cell dimensions were obtained by a least-squares fit of 24 centered reflections in the range of $24 \leq \theta \leq 33^{\circ}$.

Intensity data were collected using the $\theta-2 \theta$ technique to a maximum $2 \theta$ of $140^{\circ}$. The scan width, $\Delta \theta$, for each reflection was $0.80+0.15 \tan \cdot \theta$. An aperture with a height of 4 mm and a variable width, calculated as $(2.0+0.5 \tan \cdot \theta) \mathrm{mm}$, was located 173 mm from the crystal. Reflections were first measured with a scan of $8.24^{\circ} / \mathrm{min}$. The rate of the final scan was calculated from the preliminary scan results so that the ratio $I / \sigma(\mathrm{I})$ would be at least 40 but the maximum scan time would not exceed 60 seconds. If in a preliminary scan $\mathrm{I} / \sigma(\mathrm{I})<2$, this measurement was used as the datum. Scan rates varied from 1.27 to $8.24^{\circ} / \mathrm{min}$. Of the 96 steps in the scan, the first and the last 16 steps were considered to be background. During data collection the intensities of three standard reflections were monitored after every hour of X-ray exposure. No decay was observed. In addition, three orientation standards were checked after 100 reflections to check the effects of crystal movement. If the standard deviation of the $h, k$, and $l$ values of any orientation reflection exceeded 0.06 , a new orientation matrix was calculated on the basis of the recentering of the 24 reference reflections.

Intensities were corrected for Lorentz and polarization and absorption effects. All non-hydrogen atoms were found by using the results of the SHELXS-86 direct method analysis ${ }^{1}$. After several cycles of refinements ${ }^{2}$ the positions of the hydrogen atoms were calculated, and added to the refinement process. Refinement proceeded to convergence by minimizing the function $\Sigma \mathrm{W}\left(\left|\mathrm{F}_{\mathrm{o}}\right|-\left|\mathrm{F}_{\mathrm{c}}\right|\right)^{2}$. A final difference Fourier synthesis map showed several peaks less than $0.8 \mathrm{e} / \AA^{3}$ scattered about the unit cell without a significant feature.

The discrepancy indices, $R=\Sigma| | \mathrm{F}_{\mathrm{O}}\left|-\left|\mathrm{F}_{\mathrm{c}}\right|\right| / \Sigma\left|\mathrm{F}_{\mathrm{o}}\right|$ and $R_{\mathrm{W}}=\left[\Sigma \mathrm{W}\left(\left|\mathrm{F}_{\mathrm{o}}\right|-\right.\right.$ $\left.\left.\left|\mathrm{F}_{\mathrm{c}}\right|\right)^{2} / \Sigma \mathrm{W}\left|\mathrm{F}_{\mathrm{o}}\right|^{2}\right]^{1 / 2}$ are presented with other pertinent crystallographic data in the following Table.
(1) Sheldrick, G.M., Crystallographic Computing 3, Oxford University Press, pp. 175189 (1985).
(2) All crystallographic computing was done on a VAX 9000 computer at the Hebrew University of Jerusalem, using the TEXSAN structure Analysis Software.
formula
space group
$a, \AA$b, $\AA$c. $\AA$
$\mathrm{C}_{40} \mathrm{H}_{44} \mathrm{~S}_{2} \cdot 1 / 2 \mathrm{C}_{5} \mathrm{H}_{5} \mathrm{~N}$
Cmca
25.424 ..... (4)11.274 (2)
$V, \AA^{3}$ ..... 4037.5 (8)
Z ..... 4
$\rho_{\text {calcd. } .} \mathrm{g} \mathrm{cm}^{-3}$ ..... 1.03
$\mu\left(\mathrm{CuK}_{\alpha}\right), \mathrm{cm}^{-1}$ ..... 13.42
no. of unique reflections ..... 2017
no. of reflections with $\geq 3 \sigma_{I}$ ..... 1592
R ..... 0.056
$R_{\mathrm{w}}$ ..... 0.081

## X-ray Crystal Structure Analysis of 4

Data were measured on a PW1100/20 Philips Four-Circle Diffractometer. MoK ${ }_{\alpha}$ ( $\lambda=0.71069 \AA$ ) radiation with a graphite crystal monochromator in the incident beam was used. The unit cell dimensions were obtained by a least-squares fit of 24 centered reflections in the range of $10 \leq \theta \leq 14^{\circ}$. Intensity data were collected using the $\omega-2 \theta$ technique to a maximum $2 \theta$ of $46^{\circ}$. The scan width, $\Delta \omega$, for each reflection was $1.00+0.35$ $\tan \cdot \theta$ with a scan speed of $3.0 \mathrm{deg} / \mathrm{min}$. Background measurements were made for a total of 10 seconds at both limits of each scan. Three standard reflections were monitored every 60 minutes. No systematic variatios in intensities were found.

Intensities were corrected for Lorentz and polarization effects. All non-hydrogen atoms were found by using the results of the SHELXS-86 direct method analysis ${ }^{1}$. After several cycles of refinements ${ }^{2}$ the positions of the hydrogen atoms were calculated, and added to the refinement process. Refinement proceeded to convergence by minimizing the function $\operatorname{\Sigma w}\left(\left|F_{0}\right|-\left|F_{c}\right|\right)^{2}$. A final difference Fourier synthesis map showed several peaks less than $0.7 \mathrm{e} / \AA^{3}$ scattered about the unit cell without a significant feature.

The discrepancy indices, $R=\Sigma| | F_{o}\left|-\left|F_{\mathrm{C}}\right|\right| / \Sigma\left|\mathrm{F}_{\mathrm{o}}\right|$ and $R_{\mathrm{w}}=\left[\Sigma \mathrm{w}\left(\left|\mathrm{F}_{\mathrm{o}}\right|-\right.\right.$ $\left.\left.\left|F_{c}\right|\right)^{2} / \Sigma \mathrm{w}\left|F_{0}\right|^{2}\right]^{1 / 2}$ are presented with other pertinent crystallographic data in the following Table .
(1) Sheldrick, G.M., Crystallographic Computing 3, Oxford University Press, pp. 175189 (1985).
(2) All crystallographic computing was done on a VAX 9000 computer at the Hebrew University of Jerusalem, using the TEXSAN Structure Analysis Software.

## Crystallographic Data for 4

formula $\mathrm{C}_{40} \mathrm{H}_{44} \mathrm{~S}_{4}$
space group ..... P $\overline{1}$
$a, \AA$ ..... 13.378 (2)
$b, \AA$ ..... 15.227 (3)
c, $\AA$ ..... 11.719 (2)
$\alpha$, deg. ..... 104.44 (1)
$\beta$, deg. ..... 110.02 (1)
$\gamma$, deg. ..... 95.43 (1)
$V, \AA^{3}$ ..... 2129.2 (8)
Z ..... 2
$\rho_{\text {calcd. } .} \mathrm{g} \mathrm{cm}^{-3}$ ..... 1.02
$\mu\left(\mathrm{MoK}_{\alpha}\right), \mathrm{cm}^{-1}$ ..... 2.35
no. of unique reflections ..... 5927
no. of reflections with $\mathbb{\geq} 3 \sigma_{I}$ ..... 4099
R ..... 0.062
$R_{\mathrm{w}}$ ..... 0.086


Figune $s_{1}$


Figure $s_{2}$

